

OPI1268S

Features:

- 20kV Isolation
- 2 Mbit/s transfer rate
- t_{PHL} - $t_{PLH} \le 50$ ns typical
- Creepage path: 24 mm
- TTL Compatible
- 6 Axis / 10G_{RMS} load rating

Certifications:

- UL File E58730
- Vde File 40031798
- EN 60079-0:2012/A11:2013 EN60079-11:2012 (IEC 60079-11:2011 Edition 6)
- IP65 Rated
- ATEX Certification Exia IIc Ga

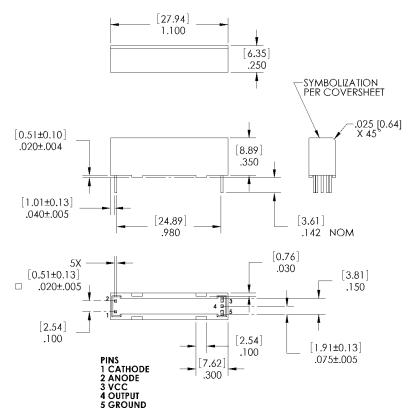


Description:

The OPI1268S is a high voltage isolator with a digital output that is capable of high speed data transmission. The input of the OPI1268 consists of a high-efficiency GaAlAs LED with a peak wavelength of 850 nm, which is optically coupled to the output optical IC. A photologic device in the output IC detects the incoming modulated light and converts it to a proportionate current. This current is fed into a high-gain linear amplifier which temperature, current and voltage compensated. The result is a highly stable digital output with an open collector inverter configuration. This device produces DC and AC voltage isolation between the input and output circuitry while providing TTL signal integrity.

Applications:

- Transportation Systems
- PC Board Power Systems
- Hybrid Vehicle Systems
- Medical Systems
- Control Systems



NOTE:

- 1. DIMENSIONS ARE ± .010 [.25] UNLESS OTHERWISE NOTED.
- 2. DIMENSIONS ARE IN INCHES [MM].



Ordering Information										
Part Number	LED Peak Wavelength	Sensor Photologic®	Isolation Voltage (kV)DC	t _{PLH} / t _{PHL} Max (ns)	I _F (mA) Typ / Max	V _{CE} (V) Max	Lead Length (mm)	Lead Spac- ing (mm)		
OPI1268S	850 nm	Open Collector	20	100	10 / 50	18	3.6	2.0		



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Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

-50° C to +100° C
-50° C to +100° C
20 KVDC
260° C
30 mA
3.0 A
3.0 V
100 mW
7 V
40 mW
18 V
25 mA

Electrical Characteristics (T_A = 0° C to 70° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	МАХ	UNITS	TEST CONDITIONS			
Input Diode									
V _F	Forward Voltage		1.4	1.8	V	I _F = 20 mA			
I _R	Reverse Current		0.1	100	μА	V _R = 2.0 V			
Output IC ($V_{CC} = 4.5 \text{ V}$ to 5.25 V) (See OPL550 for additional information—for reference only.)									
I _{OH}	High Level Output Current	-	0.20	25	μА	I _F = 0.0 mA, V _{OH} = 18.0 V, Vcc = 5.25 V			
V _{OL}	Low Level Output Voltage	-	0.35	0.55	V	I _F = 10.0 mA, I _{OL} = 8.0 mA, Vcc = 4.5 V			
I _{CCH}	High Level Supply Current	-	5.5	7	A	I _F = 0, Vcc = 5.25V			
I _{CCL}	Low Level Supply Current	-	7.5	10	mA	I _F = 10.0 mA, Vcc = 5.25 V			
Coupled Ch	Coupled Characteristics (V _{CC} = 5 V)								
C _{IO}	Coupling Capacitance	-	-	2	pF	Input and output leads shorted.			
t _{PLH}	Propagation Delay to Low Output Level	-	50	100	nc	See Figure 1			
t _{PHL}	Propagation Delay to High Output Level	-	50	100	ns				
I _{ISO}	Isolation Leakage Current		-	1	μА	VISO = @ 7kV RMS			
I _F +	LED Positive Going Threshold Current	0.8	1.7	5.0	mA	V _{CC} = 5V, I _{OL} = 8.0mA			
dv/dt	Voltage Spike Immunity		30		kV/μs				

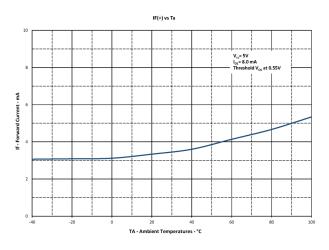
Notes:

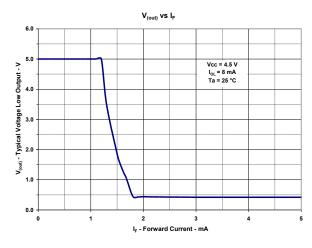
- (1) Derate LED linearly 1.33 mW/°C above 25°C.
- (2) UL registered under E58730.
- (3) RMA flux is recommended. The duration can be extended to 10 seconds maximum when flow soldering.
- (4) Derate linearly 0.54m W/°C above 25°C.
- (5) Measured with input leads shorted together and output leads shorted together in air with a maximum relative humidity of 50%.

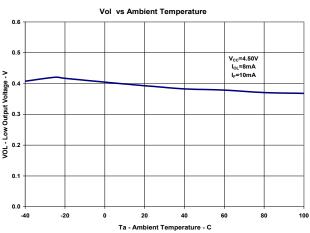


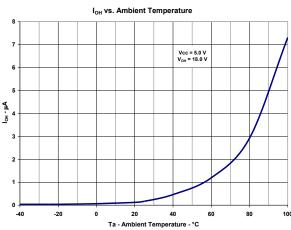
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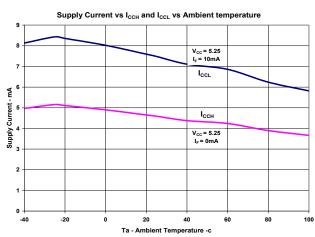
Typical Performance Curves

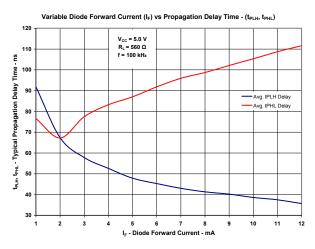














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CIRCUIT VALUES

Condition #1: $V_{CC} = 5.0V$, $I_F = 30mA$, $R_L = 560$ Ohms

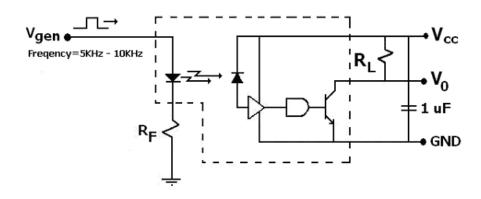
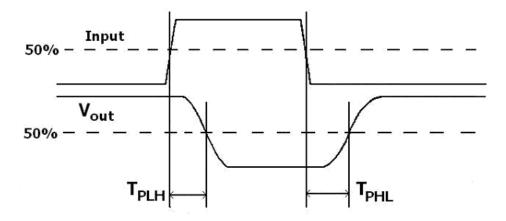


Figure 1



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